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Investigation of multilayer ZnO:Al/Ag/ZnO:Al transparent conductive films prepared by magnetron sputtering for solar applications

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FHR Anlagenbau GmbH

Headquarter near the city of Dresden, Germany
Office rooms and more than 6,000 sqm assembling spaces for
thin film deposition equipment



Outline

- ▴ Introduction
 - ▴ TCO for solar cells
- ▴ Experiment
 - ▴ Magnetron sputtering of AZO/Ag/AZO layer stack
 - ▴ Optical and electrical properties
 - ▴ Adhesion improvement
 - ▴ Morphological studies
 - ▴ Thermal stability
- ▴ FHR tools for thin film deposition
- ▴ Conclusions

Introduction

▴ PV - technologies

Silicon Wafer Technologies

Monocrystalline
Silicon



16-21%

Polycrystalline
Silicon



14 -17%

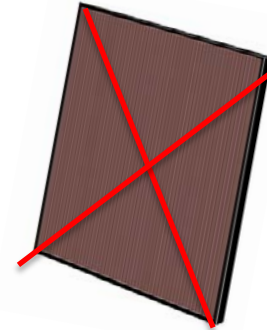
Thin Film Technologies

Cl(G)S, CdTe



13 -16%

Thin Film Silicon



8-10%

➤ No market potential due to low efficiency

Introduction

▴ PV - technologies

Silicon Wafer Technologies

Monocrystalline
Silicon



16-21%

Polycrystalline
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14 -17%

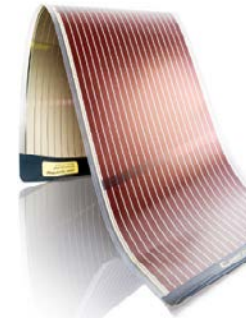
Thin Film Technologies

Cl(G)S, CdTe



13 -16%

OPV & Perovskites



7-10%

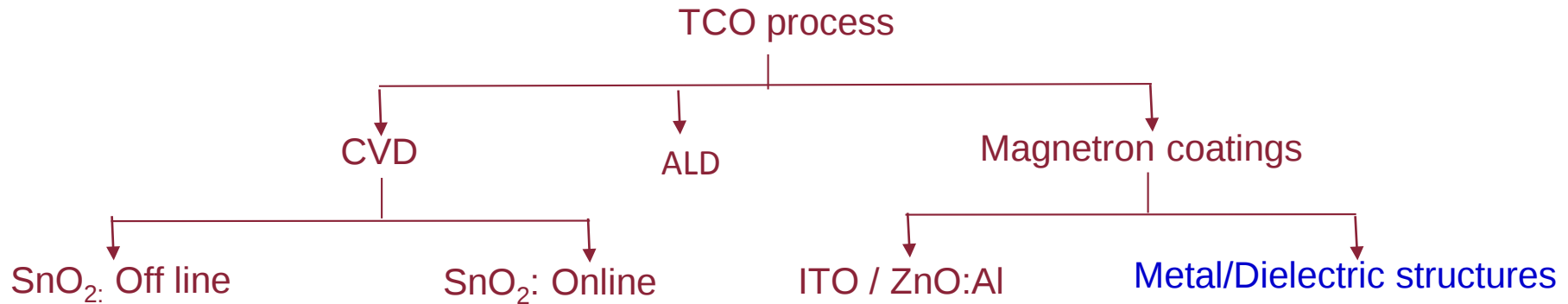
- Flexible foil
- Building Integrated PV applications
- Require high performing TCOs

PV-TCO: Electrode requirements

- ⚠ Electrical properties: Low Sheet resistance ($R_{sh} < 10 \text{ ohm/sq}$)
- ⚠ Optical properties
 - ⚠ High transmittance ($TL > 80\%$)
 - ⚠ Aesthetic colours (Neutral colour for BIPV)
- ⚠ Mechanical properties
 - ⚠ Good adhesion on glass, foil etc
- ⚠ Compatibility with solar cell fabrication process
 - ⚠ Temperature (up to $200 \text{ }^{\circ}\text{C}$)
 - ⚠ No delamination / Long term durability
- ⚠ Low cost potential
 - ⚠ Simple manufacturing
 - ⚠ Easily available materials

PV-TCO: Deposition methods

- ▲ Wide range of choices for TCO deposition



PV-TCO: Deposition methods

▲ Wide range of choices for TCO deposition

Material	Method	Advantages	Disadvantage
SnO ₂ : F (FTO)	APCVD	Inexpensive	- Durability against Hydrogen plasma - Chemical etching
In ₂ O ₃ : SnO ₂ (ITO)	Sputter	Electrical and Optical properties	Most successful / But Expensive coating material
ZnO:Al (AZO)	LPCVD	- Easy Chemical etching - Good durability against Hydrogen plasma	- Degradation in atmosphere - Post annealing treatment (cold sputtering)
	Sputter		
New TCOs	Sputter	- No degradation in atmosphere - Non toxic (Cd like materials / Ex: CdSnO₄) - No or very little In (cost related) - Good durability (Cell fabrication, in-build stress etc related)	

FHR product focus

Vacuum coating equipment & Sputtering targets

See also - Dr. Reinhard Fendler: Session 3.2.2 Room 3812/3 Wednesday, 26 October 11:45

“Large area deposition of contact films by magnetron sputtering”



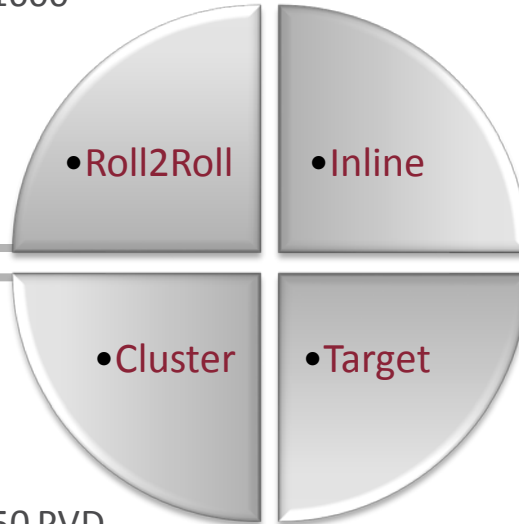
▲ FHR.Roll.1600-PVD



▲ FHR.Line.2500-TCO



▲ FHR.Star.150-PVD



Experiment

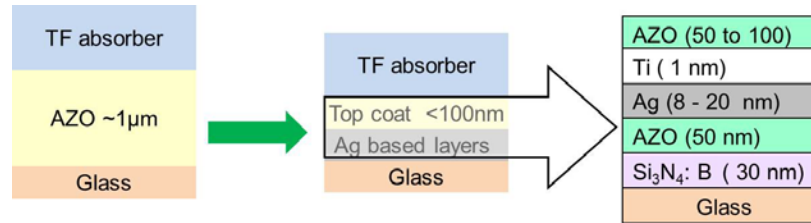
- △ AZO and Ag deposition by magnetron sputtering
- △ In-line magnetron sputtering machine at SERIS –NUS (FHR Line 540)



- △ Equipment capabilities
 - △ Two process chambers
 - △ Number of sputter sources: 6 (Planar, Cylindrical targets / DC and DC+ sources)
 - △ Maximum substrate temperature: 300 °C
 - △ Substrate size: 30 cm x 40 cm
 - △ Complete in-line process

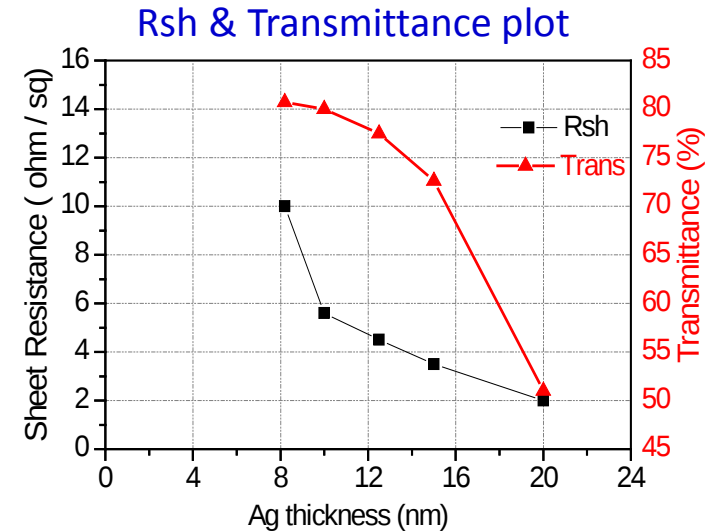
Experiment (cont'd)

▲ AZO/Ag/AZO development



▲ With increasing Ag thickness

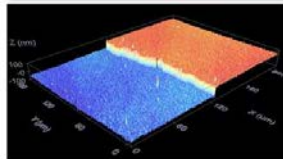
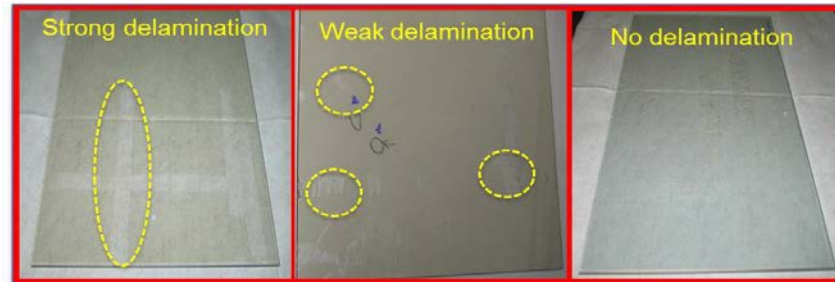
- ▲ Sheet resistance decrease
- ▲ Transmittance decrease
- ▲ Optimum Ag thickness: 8 to 10 nm → TL ~ 80%



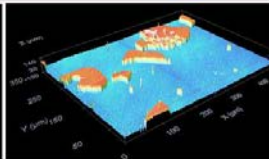
Experiment (cont'd)

Adhesion improvement

- AZO deposition pressure influence the adhesion
- Adhesion test → standard scotch tape test

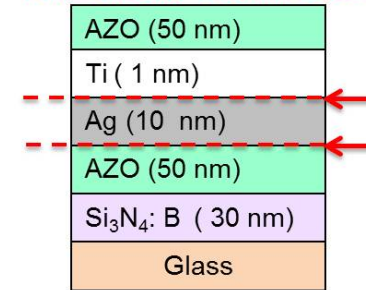


Ag & AZO removed



Partial removal of Ag & AZO

Two weak interfaces

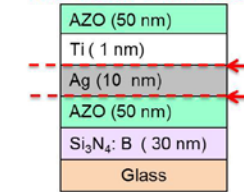


- High pressure deposited AZO retains good adhesion

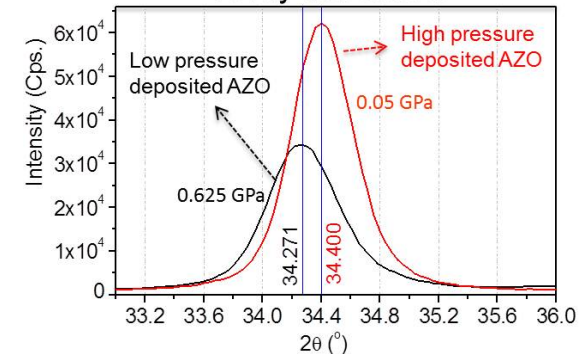
Experiment (cont'd)

- ▲ Adhesion improvement
 - ▲ AZO deposition pressure influence the adhesion
 - ▲ Adhesion test → standard scotch tape test
- ▲ Sample with delamination
 - ▲ XRD peak shifted towards lower angle
 - ▲ Indication of compressive stress
 - ▲ Estimated stress value: 0.625 GPa
- ▲ Sample with GOOD adhesion
 - ▲ XRD peak observed at 34.4°
 - ▲ Nearly stress free films
 - ▲ Estimated stress value 0.05 GPa
- ▲ High pressure deposited AZO retains good adhesion

Two weak interfaces



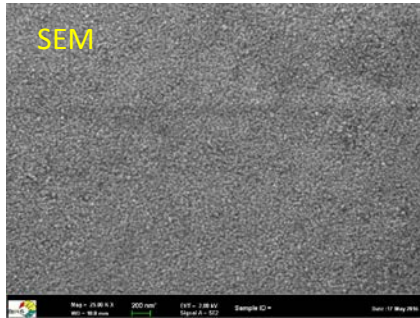
X-ray diffraction



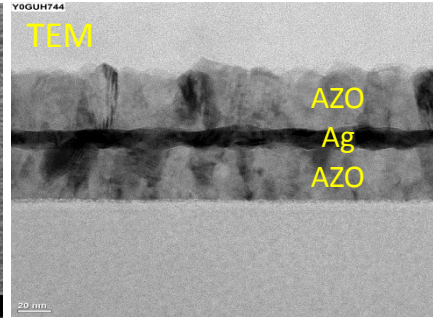
Experiment (cont'd)

▴ Morphology (SEM & TEM)

- ▴ Smooth surface → suited for further layer deposition & solar cell processing



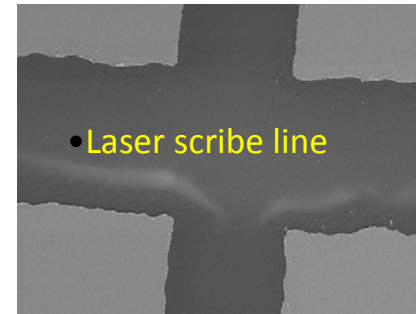
- Smooth surface



- Thin & continuous Ag layer

▴ Module making

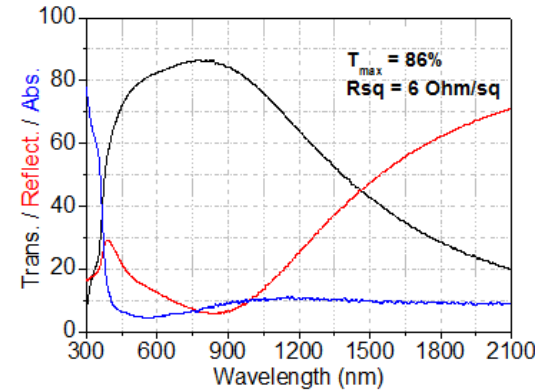
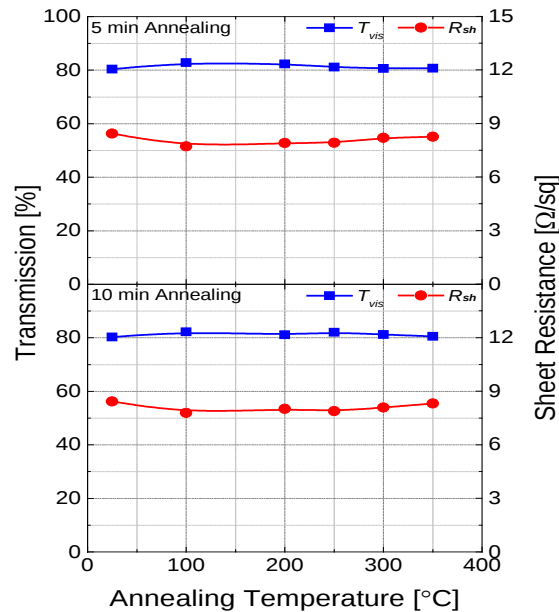
- ▴ compatibility for laser processing



- No difficulties for laser scribing/patterning

Experiment (cont'd)

Thermal stability & Annealing studies



- Layer stack is suitable for high temperature cell fabrication process
- Annealing does not affect optical and electrical properties

Summary

- ▲ AZO/Ag/AZO can be an alternative material for electrode application for making thin film solar cells → high performing and low cost potential
- ▲ Adhesion issue can be solved by adjusting the AZO deposition conditions
- ▲ Stack is more suitable for newly emerging OPV and perovskite technologies for BIPV application
 - ▲ Low-E functionality is an added advantage for smart building concepts
- ▲ Stack can be easily produced in existing production lines without huge investments
- ▲ Next step: Fabrication of solar cells

Research collaboration



Professor Armin ABERLE (left), CEO of the Solar Energy Research Institute of Singapore (SERIS) at the National University of Singapore, and Dr Reinhard FENDLER, CEO of FHR Anlagenbau GmbH. © FHR/SERIS 2013

- ▴ FHR is closely working with the Solar Energy Research Institute of Singapore (SERIS-NUS) for the development of next generation TCOs

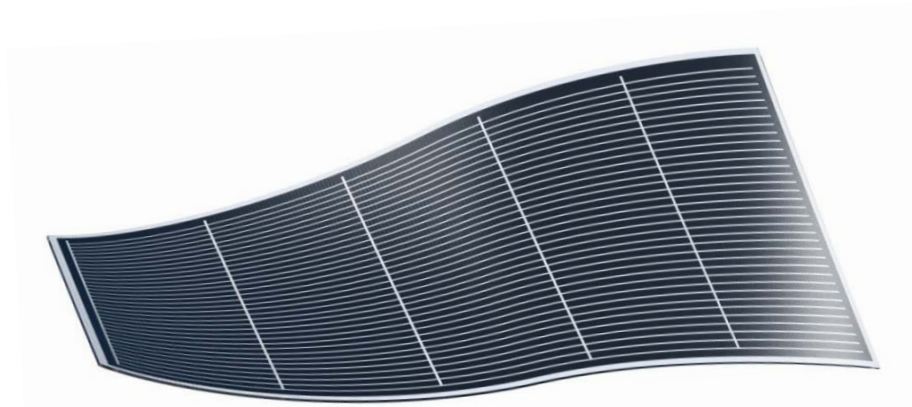
The Thin Film Company



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semi

